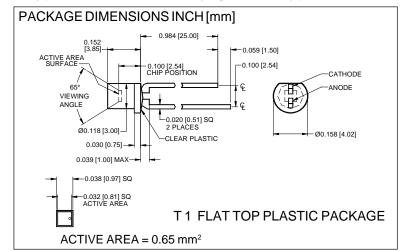
PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive **DETECTORS INC.** Type PDB-C131, with daylight filter Type PDB-C131F





FEATURES

- Photoconductive
- High speed
- Low cost
- Flat top, T1 package

DESCRIPTION: The **PDB-C131** detector is a 0.65 mm² planar pin photodiode packaged in a T1 flat top, water clear plastic housing. Designed for high speed, low capacitance, photoconductive applications. The **PDB-C131F** includes a daylight filter.

APPLICATIONS

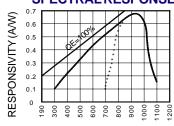
- Smoke detectors
- Light pen detectors
- TV & VCR remotes
- IRDA sensor

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS	
V_{BR}	Reverse Voltage		100	V	
T _{STG}	Storage Temperature	-40	+100	∘C	
T _o	Operating Temperature Range	-40	+80	∘C	
T _s	Soldering Temperature*		+260	°C	
IL	Light Current		0.5	mA	

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



WAVELENGTH (nm)

ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	TYP	MAX	UNITS			
I _{sc}	Short Circuit Current	H = 100 fc, 2850 K	8	10		μΑ			
I _D	Dark Current	H = 0, V _R = 10 V		2	10	nA			
R _{SH}	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$.5	5		GΩ			
TCR _{SH}	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-8		%/°C			
C _J	Junction Capacitance	H = 0, V _R = 10 V*		2	5	pF			
λrange	Spectral Application Range	(without daylight filter)**	400		1100	nm			
λр	Spectral Response - Peak			950		nm			
V _{BR}	Breakdown Voltage	I = 10 μA	50	100		V			
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		1.5x10 ⁻¹³		W/ √Hz			
tr	Response Time	$RL = 1 K\Omega V_D = 10 V$		5		nS			